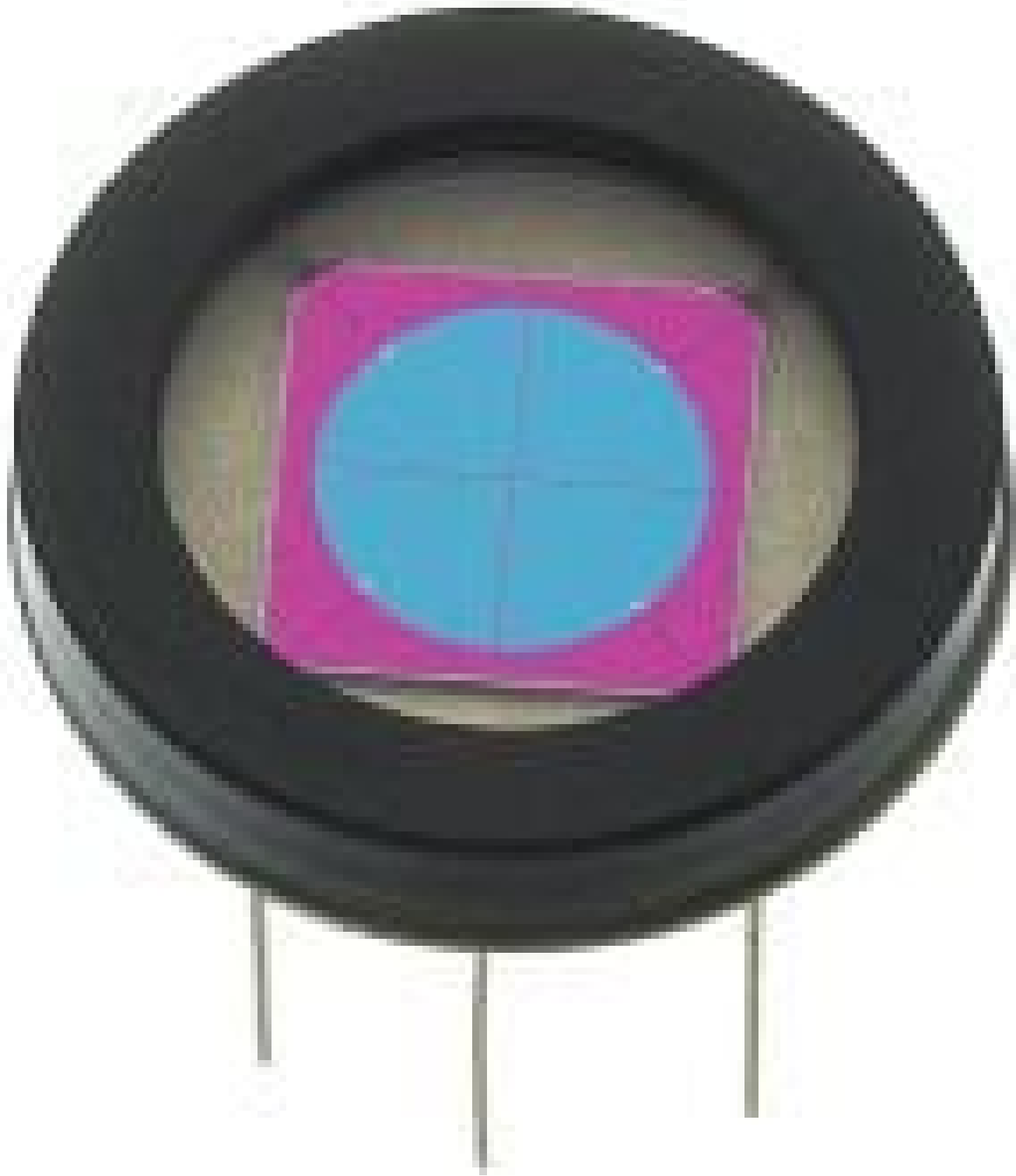


1.61mm² Four-Element UV Enhanced Segmented Photodiode



Stock **#84-613** 2 In Stock

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1

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₹7,920

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Volume Pricing	
Qty 1-4	₹7,920 each
Qty 5-9	₹7,020 each
Qty 10+	₹6,075 each
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General	
10.00	Rise Time (ns):
SPOT-4DUV	Model Number:

Physical & Mechanical Properties	
1.3 x 1.3	Size of Active Area (mm):

1.61	Active Area (mm²):
0.127	Element Gap (mm):
Electrical	
Minimum: 0.08 Typical: 0.1	Responsivity @ 970nm (AW):
40.00	Capacitance @ V _R =-10V (pF):
1.3 x 10 ⁻¹³	Noise Equivalent Power NEP (W/ Hz ^{1/2}): @ -10 V, 970nm
5.00	Maximum Reverse Voltage (V):
Maximum: 500 Typical: 100	Dark Current @ V _R =-10V (nA):
Hardware & Interface Connectivity	
41 / TO-5	Connector:
Environmental & Durability Factors	
-10 to 60	Operating Temperature (°C):
-20 to 70	Storage Temperature (°C):
Regulatory Compliance	
View	Certificate of Conformance:
United States	Country of Origin:
Edmund Optics India Private Limited	Imported By:

Product Details

- High Stability Over Temperature and Time
- Excellent Resolution, High Accuracy, Ultra-Low Dark Current
- Two or Four Separate Active Area Segments
- [Segmented InGaAs Photodiodes](#) Also Available

Segmented Photodiodes are designed for a wide variety of applications that require high stability and fast response times. Featuring position resolutions of greater than 0.1µm, Segmented Photodiodes are ideal for surface profiling, position measurement, alignment, or targeting. Segmented Photodiodes are segmented into either two or four separate active areas and have spectral response ranges from 350 – 1100nm. The segmented regions allow various measurement profiles on a single detector.